# FAIRCHILD

SEMICONDUCTOR®

FCH47N60F F085

N-Channel MOSFET

## **600V**, **47A**, **75m**Ω

### **Features**

- Typ  $r_{DS(on)}$  = 66m $\Omega$  at V<sub>GS</sub> = 10V, I<sub>D</sub> = 47A
- Typ Q<sub>q(tot)</sub> = 190nC at V<sub>GS</sub> = 10V, I<sub>D</sub> = 47A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

### Description

SuperFET<sup>TM</sup> is Fairchild's proprietary new generation of high voltage MOSFETs utilizing an advanced charge balance mechanism for outstanding low on-resistance and lower gate charge performance.

This advanced technology has been tailored to minimize conduction loss, provide superior switching performance, and withstand extreme dv/dt rate and higher avalanche energy. Consequently, SuperFET is suitable for various automotive DC/DC power conversion.

## Applications

- Automotive On Board Charger
- Automotive DC/DC converter for HEV

MOSFET Maximum Ratings T<sub>J</sub> = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
V <sub>DSS</sub>	Drain to Source Voltage		600	V
V <sub>GS</sub>	Gate to Source Voltage		±30	V
	Drain Current - Continuous (V <sub>GS</sub> =10) (Note 1)	T <sub>C</sub> =25°C	47	٨
		T <sub>C</sub> = 25°C	See Figure4	— A
E <sub>AS</sub>	Single Pulse Avalanche Energy	(Note 2)	810	mJ
Р	Power Dissipation		417	W
P <sub>D</sub>	Derate above 25°C		3.3	W/ºC
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature		-55 to + 150	°C
$R_{\theta JC}$	Thermal Resistance Junction to Case		0.3	°C/W
$R_{\theta JA}$	Maximum Thermal Resistance Junction to Ambient	(Note 3)	50	°C/W

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## Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FCH47N60F	FCH47N60F_F085	TO-247	-	-	30 units

Notes:

1: Current is limited by bondwire configuration.

2: Starting  $T_J = 25^{\circ}$ C, L = 5mH,  $I_{AS} = 18A$ ,  $V_{DD} = 100$ V during inductor charging and  $V_{DD} = 0$ V during time in avalanche

3: R<sub>0.IA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta JA}$  is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in<sup>2</sup> pad of 2oz copper.

TO-247 For current package drawing, please refer to the Fairchild website at www.fairchildsemi.com/packaging

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Electrical Characteristics T <sub>J</sub> = 25°C unless otherwise noted							
Symbol	Parameter	Test Conditions		Min	Тур	Max	Units
Off Cha	racteristics						
B <sub>VDSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = 250μA, V	′ <sub>GS</sub> = 0V	600	-	-	V
	Drain to Source Lookage Current	V <sub>DS</sub> =600V,	T <sub>J</sub> = 25 <sup>o</sup> C	-	-	10	μA
I <sub>DSS</sub>	Drain to Source Leakage Current	$V_{GS} = 0V$	$T_J = 150^{\circ}C(Note 4)$	-	-	1	mA
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS}$ = ±30V		-	-	±100	nA
	Cate to Source Threshold Voltage	V <sub>GS</sub> = V <sub>DS</sub> , I <sub>D</sub>	<sub>0</sub> = 250μA	3.0	4.0	5.0	V
r	Drain to Source On Resistance	I <sub>D</sub> = 47A,		-	66	75	mΩ
r <sub>DS(on)</sub>		V <sub>GS</sub> = 10V	$T_J = 150^{\circ}C(Note 4)$	-	180	223	mΩ
Dynami	c Characteristics						
C <sub>iss</sub>	Input Capacitance			-	5900	8000	pF
C <sub>oss</sub>	Output Capacitance			-	3200	4200	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			-	250	-	pF

C <sub>iss</sub>	Input Capacitance		– V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V, – f = 1MHz		5900	8000	pF
C <sub>oss</sub>	Output Capacitance				3200	4200	pF
C <sub>rss</sub>	Reverse Transfer Capacitance				250	-	pF
R <sub>g</sub>	Gate Resistance	f = 1MHz	f = 1MHz		1	-	Ω
Q <sub>g(ToT)</sub>	Total Gate Charge at 10V	V <sub>GS</sub> = 0 to 10V	V <sub>DD</sub> = 300V	-	190	250	nC
Q <sub>g(th)</sub>	Threshold Gate Charge	V <sub>GS</sub> = 0 to 2V			12	18	nC
Q <sub>gs</sub>	Gate to Source Gate Charge		—	-	40	-	nC
Q <sub>gd</sub>	Gate to Drain "Miller" Charge			-	96	-	nC

# **Switching Characteristics**

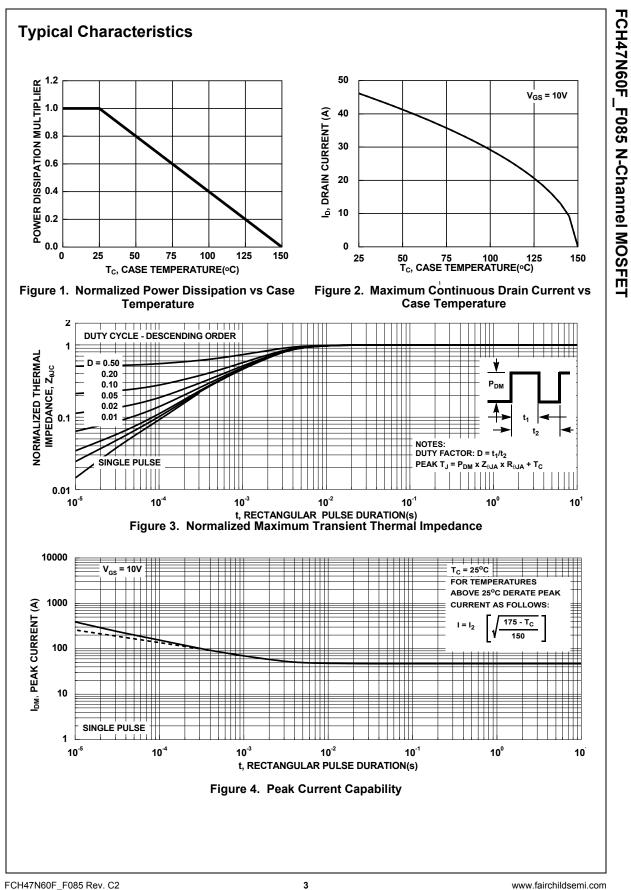
t <sub>on</sub>	Turn-On Time		-	-	410	ns
t <sub>d(on)</sub>	Turn-On Delay Time		-	110	-	ns
t <sub>r</sub>	Rise Time	V <sub>DD</sub> = 300V, I <sub>D</sub> = 47A,	-	160	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	V <sub>DD</sub> = 300V, I <sub>D</sub> = 47A, V <sub>GS</sub> = 10V, R <sub>G</sub> = 25Ω	-	540	-	ns
t <sub>f</sub>	Fall Time		-	125	-	ns
t <sub>off</sub>	Turn-Off Time		-	-	1000	ns

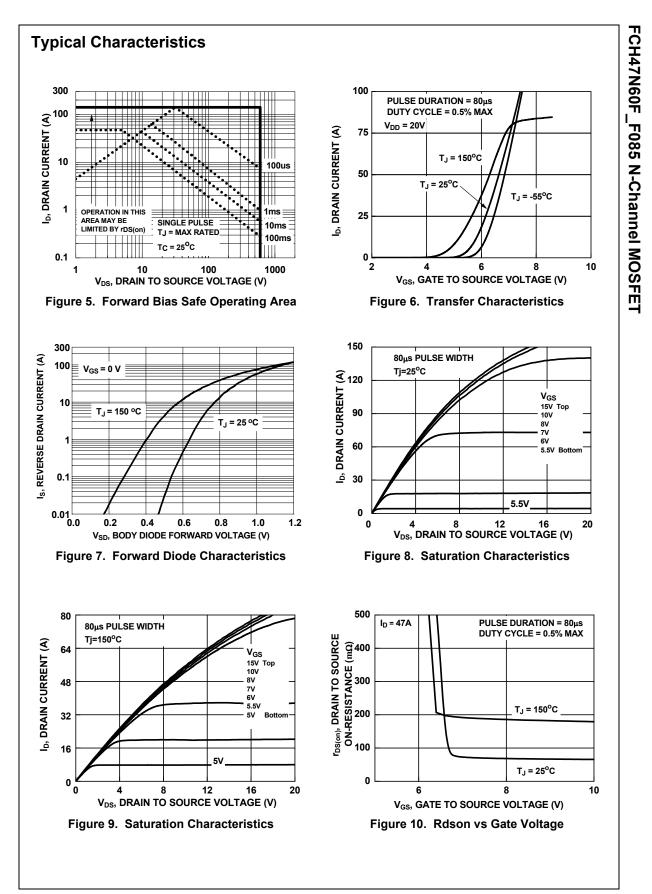
## **Drain-Source Diode Characteristics**

V.	Source to Drain Diode Voltage	I <sub>SD</sub> = 47A, V <sub>GS</sub> = 0V	-	-	1.4	V
V <sub>SD</sub>		I <sub>SD</sub> = 23.5A, V <sub>GS</sub> = 0V	-	-	1.25	V
T <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 47A, dI <sub>SD</sub> /dt = 100A/μs,	-	207	350	ns
Q <sub>rr</sub>	Reverse Recovery Charge	V <sub>DD</sub> =480V	-	2.0	3.6	uC

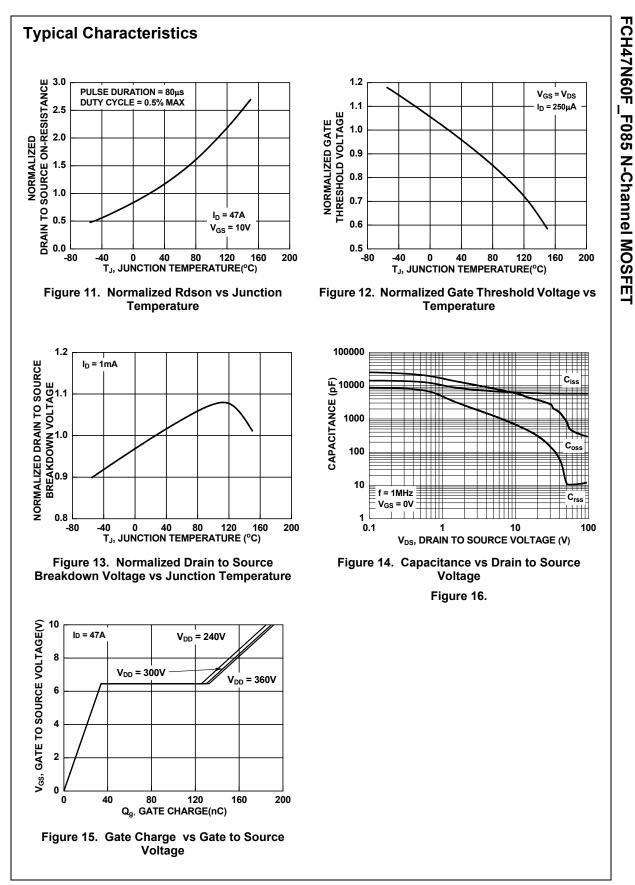
Notes:

4: The maximum value is specified by design at  $T_J$  = 150°C. Product is not tested to this condition in production.





FCH47N60F\_F085 Rev. C2



FCH47N60F\_F085 Rev. C2



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